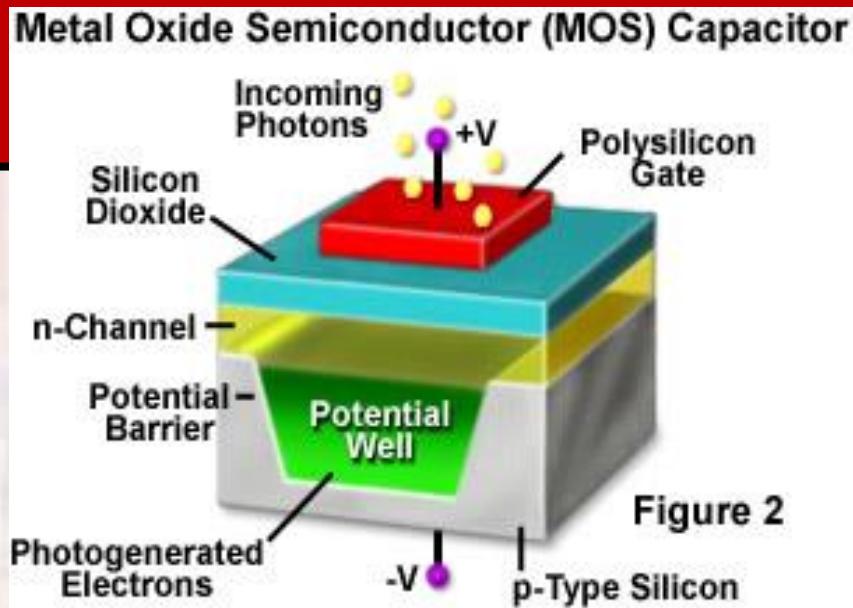


CCD Imagers

Last modified 3/20/24

CCD Imagers

- MOS Capacitor Photodetector
- Photo transparent polysilicon gate
- P-type silicon bulk (PMOS Capacitor)
- Biased in depletion mode (holes have been moved out of surface region)
 - Incident light creates hole-electron pairs
 - Holes are swept away
 - Electrons are trapped under the gate
 - Total charge trapped is proportional to the intensity of the incident light

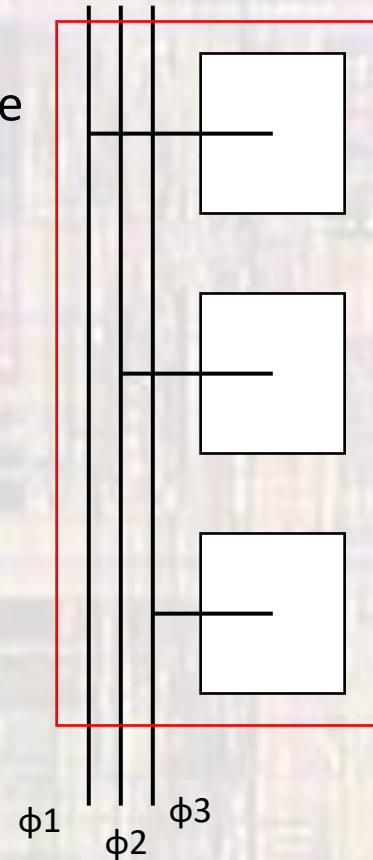


src: Nikon

CCD Imagers

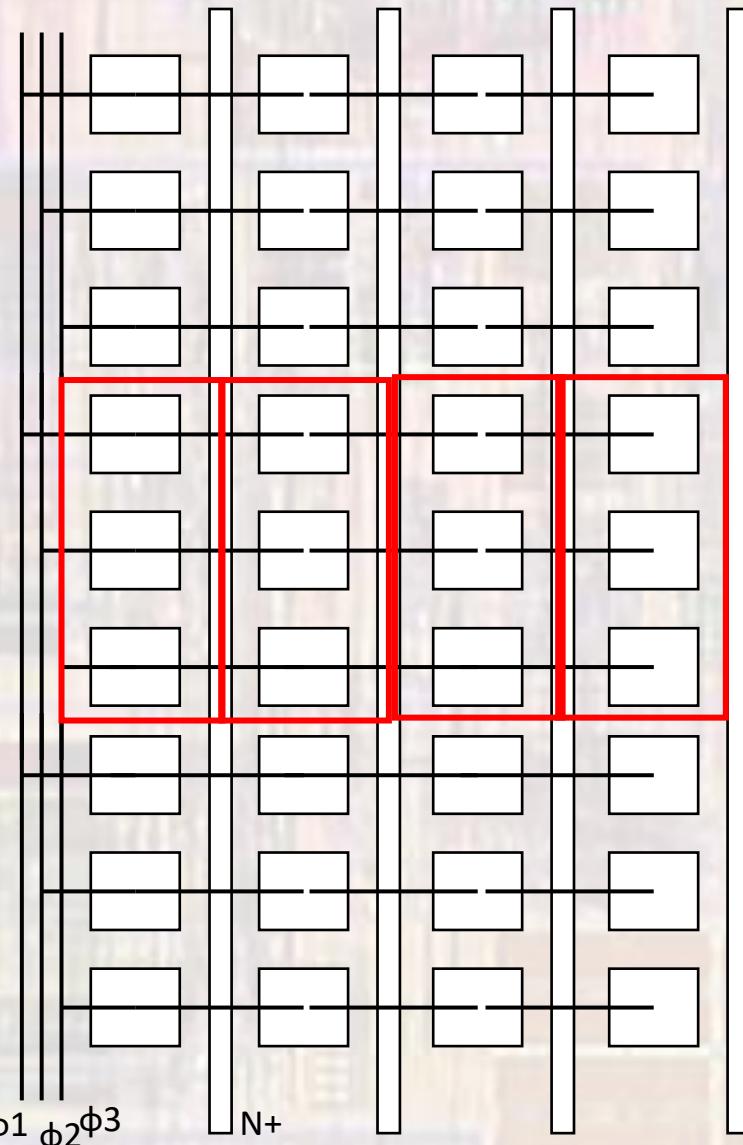
- CCD Pixel Structure

- Each pixel is configured as 3 gates
- Each gate as a separate control line



CCD Imagers

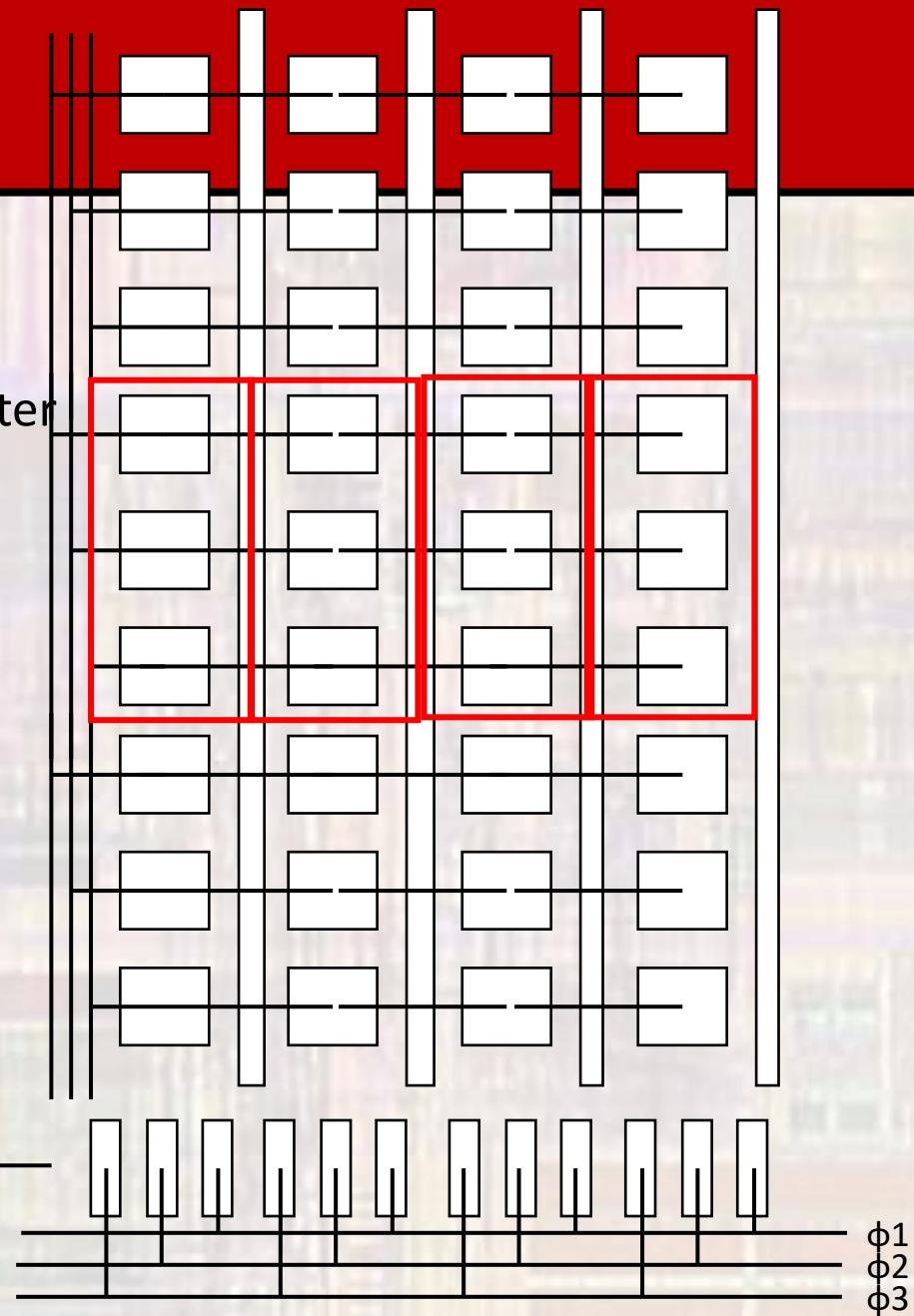
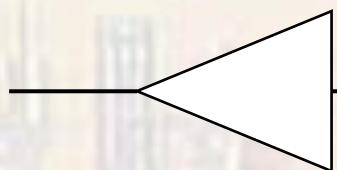
- CCD Array Structure
 - Columns of pixels
 - Separated by barrier stops



CCD Imagers

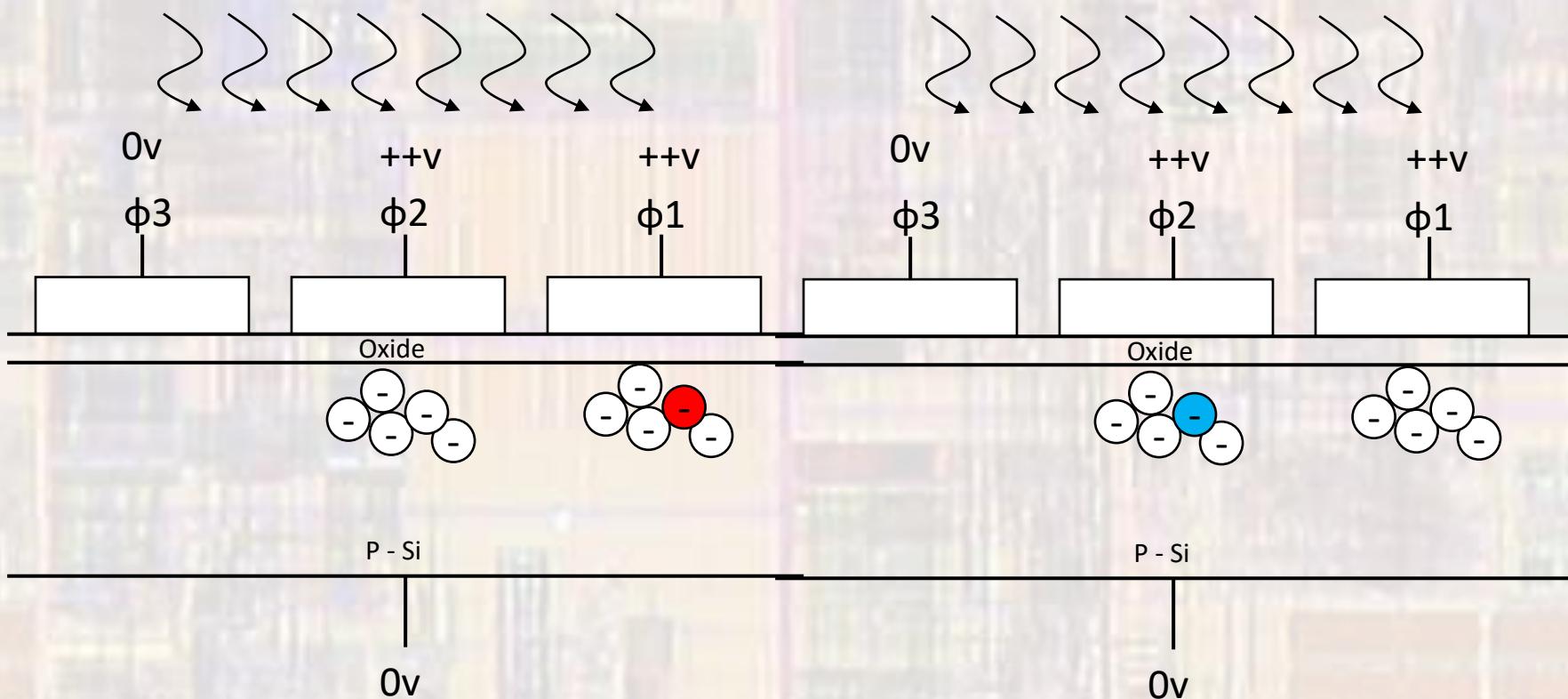
- CCD Array Structure

- Non photo-sensitive shift register
- Charge to voltage converter



CCD Imagers

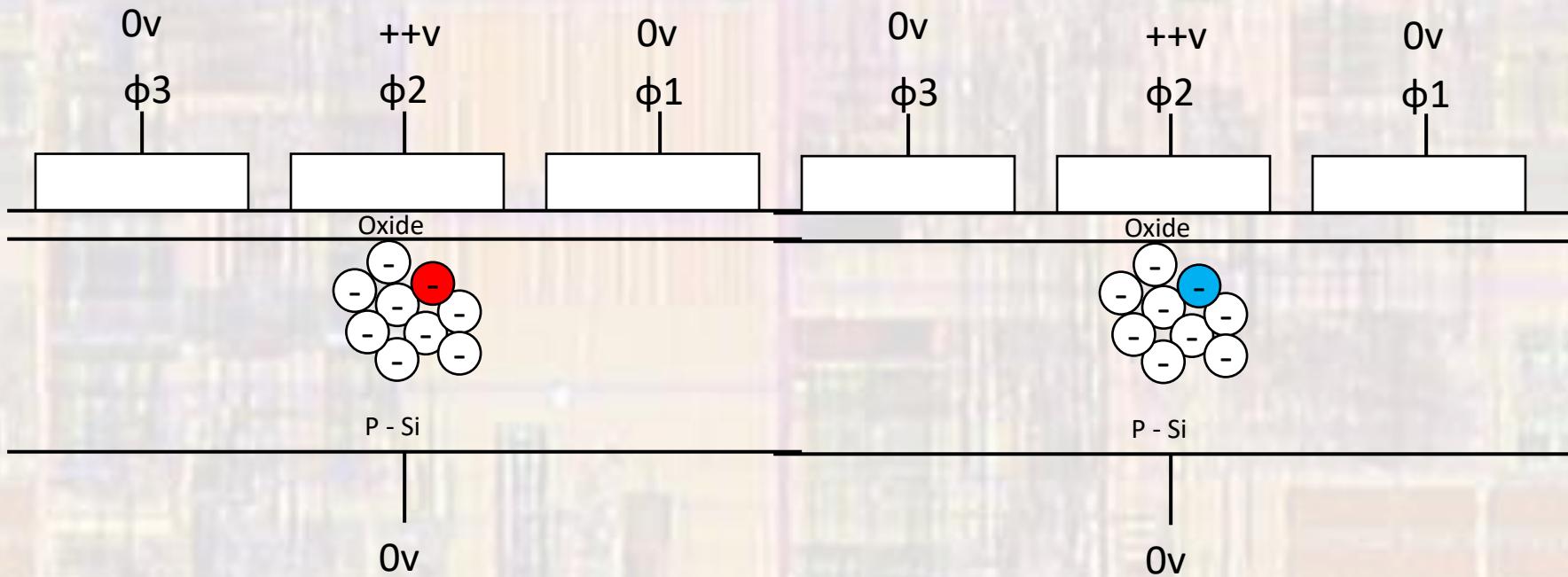
- CCD Operation



CCD Imagers

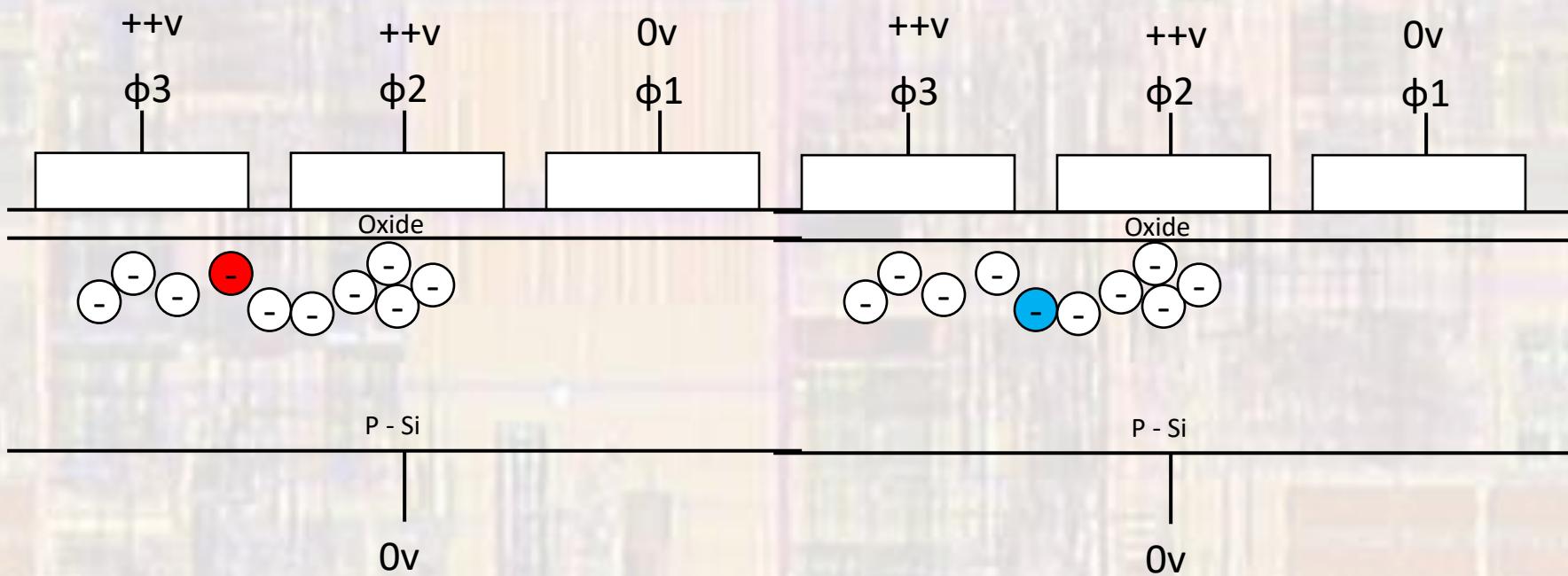
- CCD Operation

- Shutter light - off



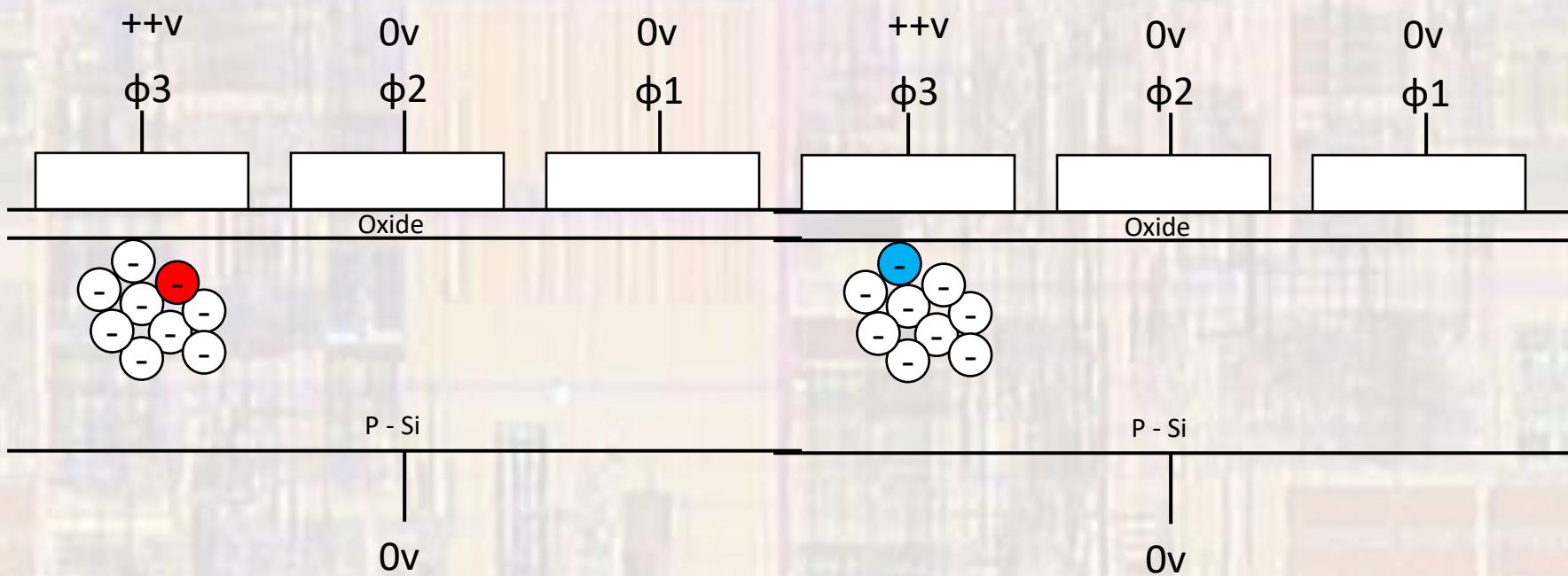
CCD Imagers

- CCD Operation



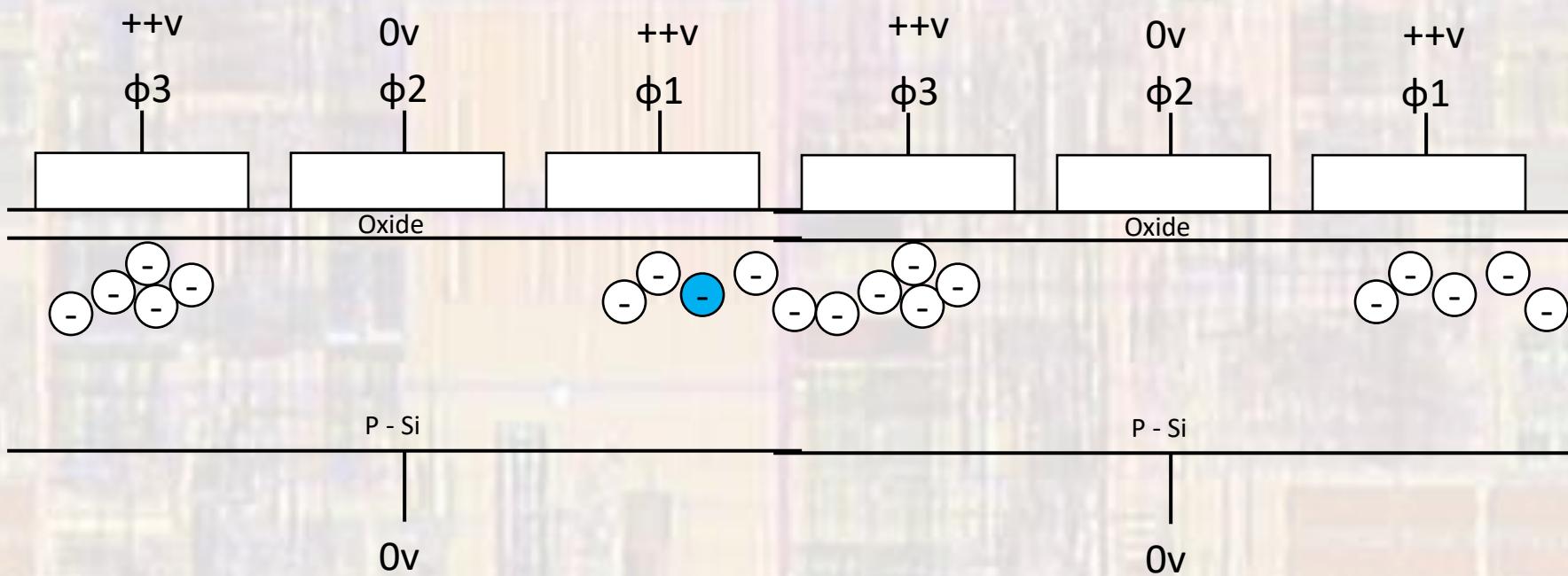
CCD Imagers

- CCD Operation



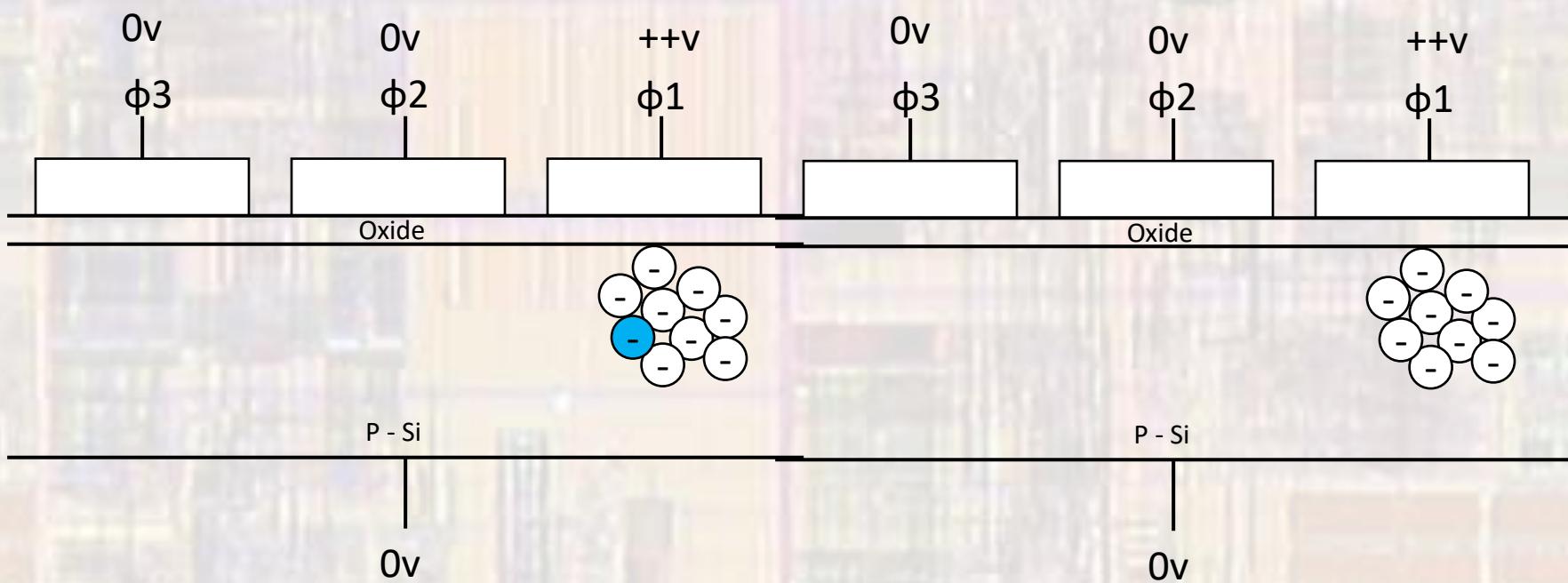
CCD Imagers

- CCD Operation



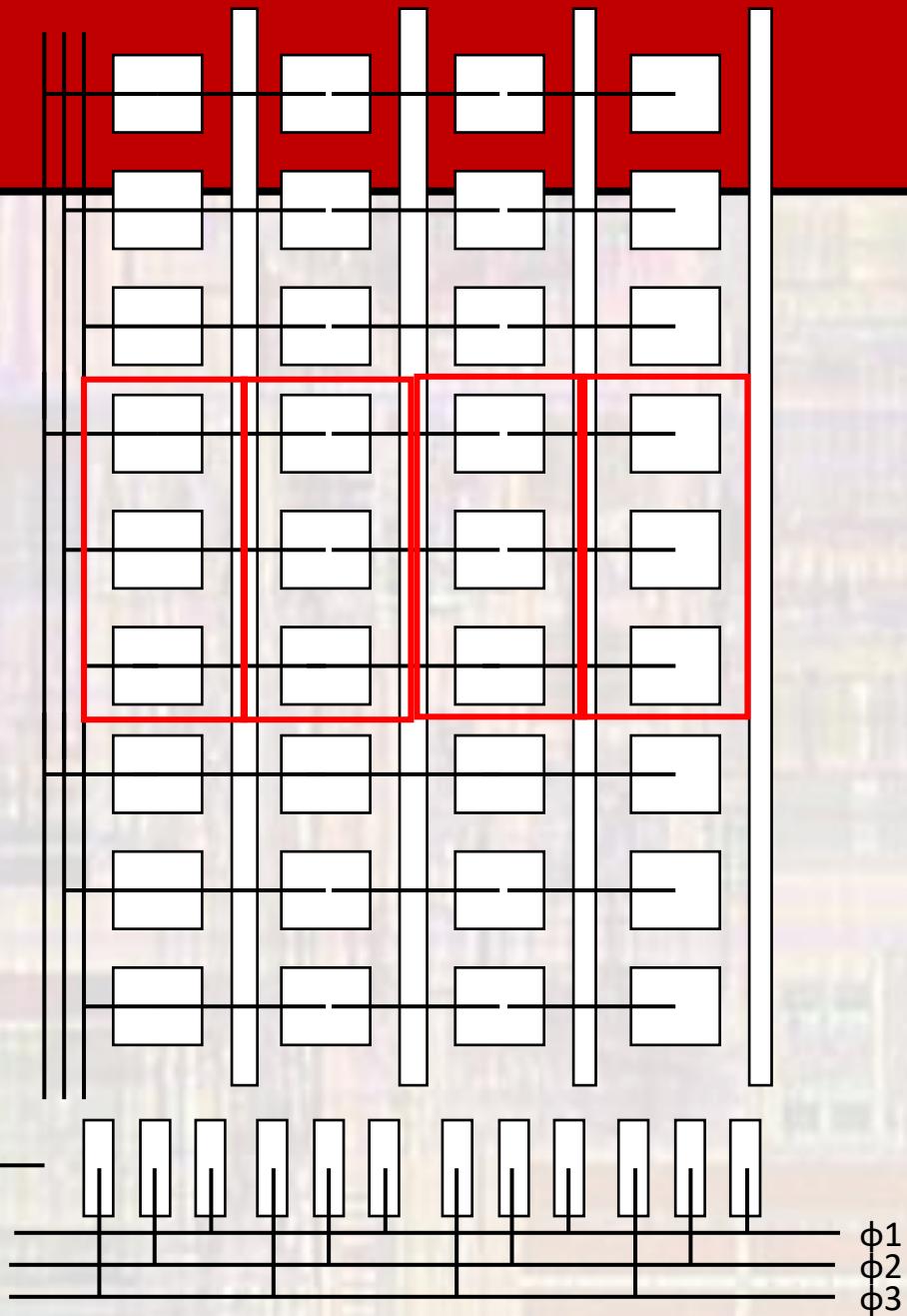
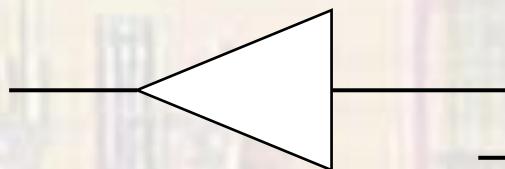
CCD Imagers

- CCD Operation



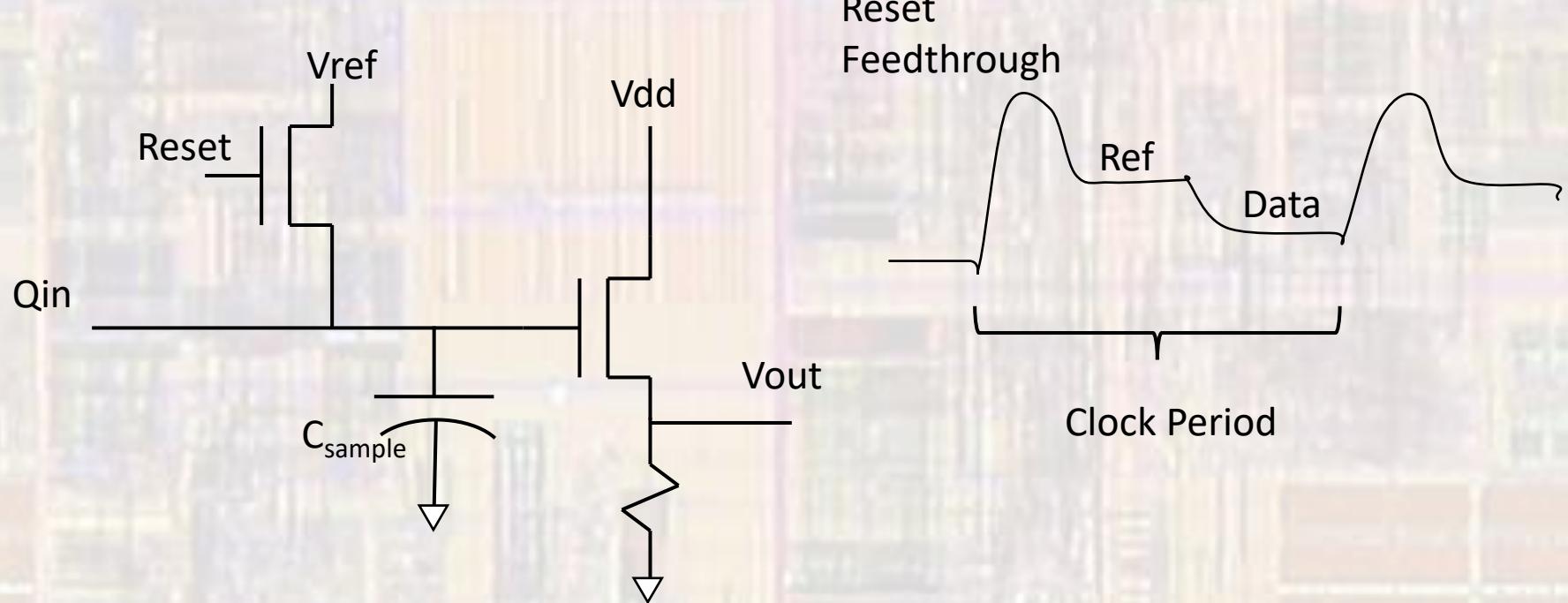
CCD Imagers

- CCD Array Structure
 - One row transferred down to the shift register
 - Entire shift register transfer out to the charge converter
 - Next row transferred down
 - ...



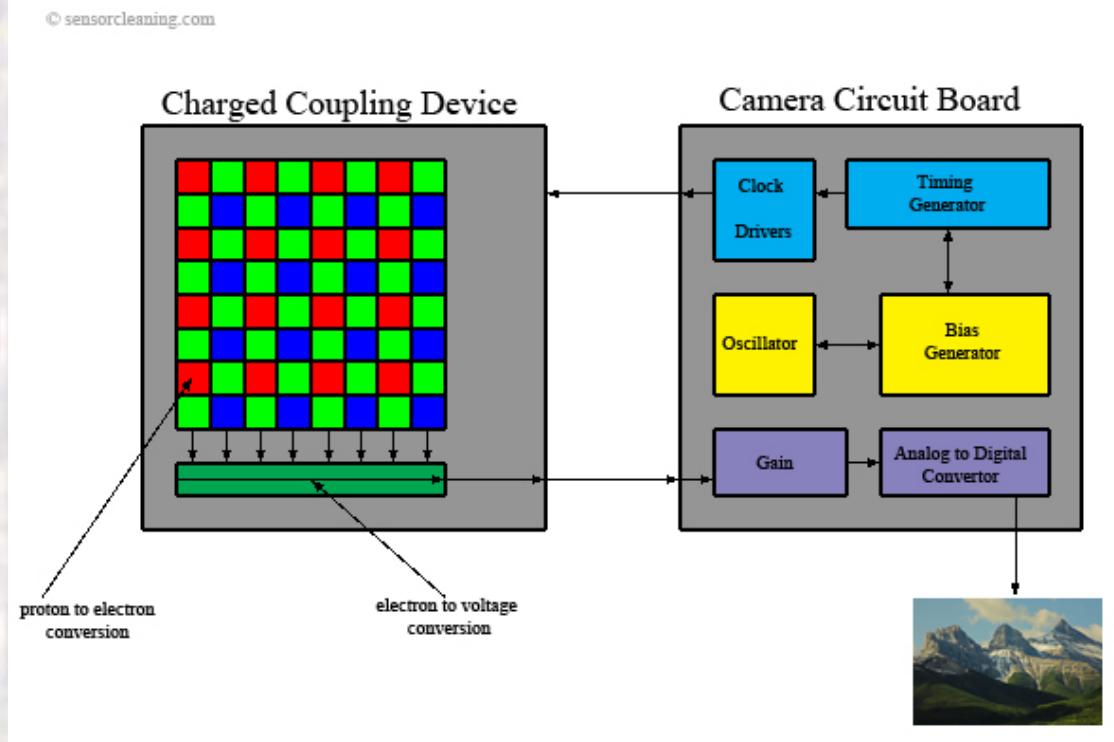
CCD Imagers

- CCD Array Structure
 - Sense amplifier



CCD Imagers

- CCD - color
 - RGB filters used to allow only 1 color to reach the detector

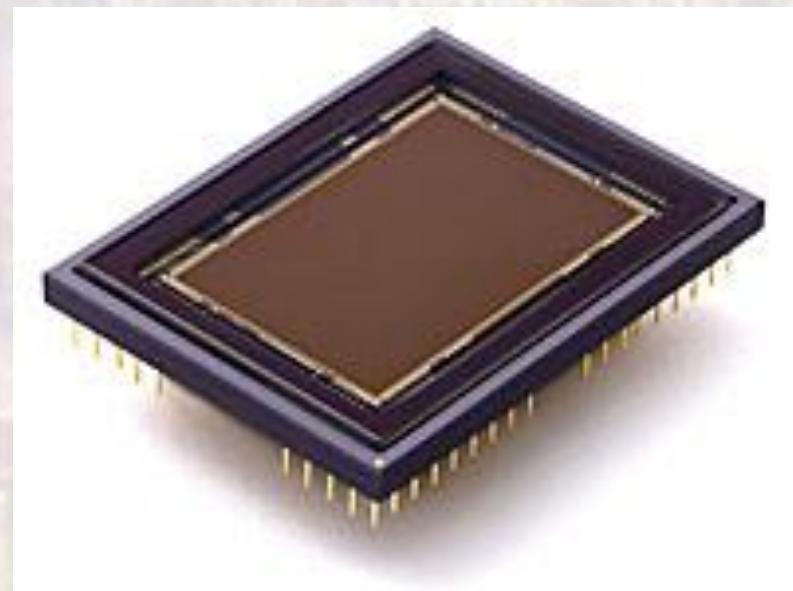


CCD Imagers

- CCD
 - Dominant structure until 1990+
 - Lowest noise
 - Slow readout
 - Dominates scientific, military applications
 - Common in medical, industrial systems, very high end photography

CCD Imagers

- CCD
 - Teledyne FTF9168C
 - 60Mpixel
 - 8956 x 6708
 - 6um x 6um pixel
 - 95% fill factor



CCD Imagers

- CCD Sensors
 - Largest single – 111Mpixel
 - Largest array – 3.2Gpixel

